



AiP74LV14

Hex Inverting Schmitt Trigger

Product Specification

Specification Revision History:

Version	Date	Description
2017-05-A1	2017-05	New
2023-04-B1	2023-04	Update the template



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1、General Description

The AiP74LV14 is a low-voltage Si-gate CMOS device that is pin and function compatible with AiP74HC14 and AiP74HCT14.

The AiP74LV14 provides six inverting buffers with Schmitt-trigger input. It is capable of transforming slowly-changing input signals into sharply defined, jitter-free output signals.

The inputs switch at different points for positive and negative-going signals. The difference between the positive voltage V_{T+} and the negative voltage V_{T-} is defined as the input hysteresis voltage V_H .

Features:

- Operating voltage: 1.0V to 5.5V
- 5.5V tolerant inputs/outputs
- Power-down mode
- Specified from -40°C to +125°C
- Packaging information: DIP14/SOP14/TSSOP14

**Ordering Information:****Tube packing specifications:**

Part number	Packaging form	Marking code	Tube quantity	Boxed tube quantity	Boxed quantity	Notes
AiP74LV14DA14.TB	DIP14	74LV14	25 PCS/tube	40 tube/box	1000 PCS/box	Dimensions of plastic enclosure: 19.0mm×6.4mm Pin spacing: 2.54mm
AiP74LV14SA14.TB	SOP14	74LV14	50 PCS/tube	200 tube/box	10000 PCS/box	Dimensions of plastic enclosure: 8.7mm×3.9mm Pin spacing: 1.27mm
AiP74LV14TA14.TB	TSSOP14	74LV14	96 PCS/tube	200 tube/box	19200 PCS/box	Dimensions of plastic enclosure: 5.0mm×4.4mm Pin spacing: 0.65mm

Reel packing specifications:

Part number	Packaging form	Marking code	Reel quantity	Boxed reel quantity	Notes
AiP74LV14SA14.TR	SOP14	74LV14	4000 PCS/reel	8000 PCS/box	Dimensions of plastic enclosure: 8.7mm×3.9mm Pin spacing: 1.27mm
AiP74LV14TA14.TR	TSSOP14	74LV14	5000 PCS/reel	10000 PCS/box	Dimensions of plastic enclosure: 5.0mm×4.4mm Pin spacing: 0.65mm

Note: If the physical information is inconsistent with the ordering information, please refer to the actual product.



2、Block Diagram And Pin Description

2.1、Block Diagram

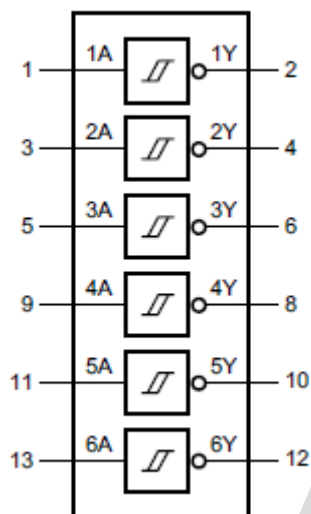


Figure 1. Logic symbol

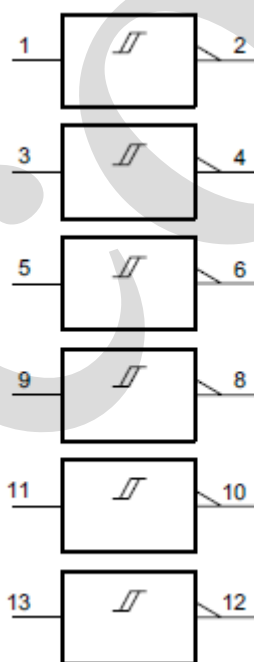


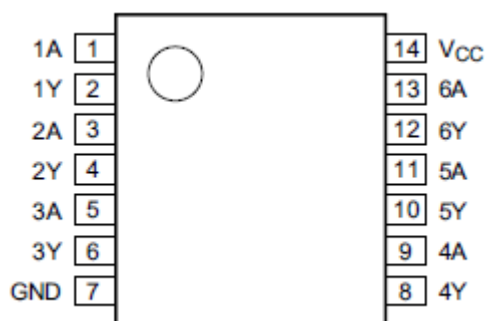
Figure 2. IEC logic symbol



Figure 3. Logic diagram for one Schmitt-trigger



2.2、Pin Configurations



2.3、Pin Description

Pin No.	Pin Name	Description
1	1A	data input
2	1Y	data output
3	2A	data input
4	2Y	data output
5	3A	data input
6	3Y	data output
7	GND	ground (0V)
8	4Y	data output
9	4A	data input
10	5Y	data output
11	5A	data input
12	6Y	data output
13	6A	data input
14	V _{CC}	supply voltage

2.4、Function Table

Input	Output
nA	nY
L	H
H	L

Note: H=HIGH voltage level; L=LOW voltage level.



3、Electrical Parameter

3.1、Absolute Maximum Ratings

(Voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Max.	Unit
supply voltage	V _{CC}	-		-0.5	+7.0	V
input clamping current	I _{IK}	V _I < -0.5V or V _I > V _{CC} +0.5V		-	±20	mA
output clamping current	I _{OK}	V _O < -0.5V or V _O > V _{CC} +0.5V		-	±50	mA
output current	I _O	V _O = -0.5V to (V _{CC} +0.5V)		-	±25	mA
supply current	I _{CC}	-		-	50	mA
ground current	I _{GND}	-		-50	-	mA
storage temperature	T _{stg}	-		-65	+150	°C
total power dissipation	P _{tot}	-		-	500	mW
Soldering temperature	T _L	10s	DIP	245		°C
			SOP/TSSOP	260		

3.2、Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
supply voltage	V_{CC}	-	1.0	3.3	5.5	V
input voltage	V_I	-	0	-	V_{CC}	V
output voltage	V_O	-	0	-	V_{CC}	V
ambient temperature	T_{amb}	-	-40	-	+125	°C

Note: The static characteristics are guaranteed from $V_{CC}=1.2V$ to $V_{CC}=5.5V$, but LV devices are guaranteed to function down to $V_{CC}=1.0V$ (with input levels GND or V_{CC}).



3.3、Electrical Characteristics

3.3.1、DC Characteristics 1

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level output voltage	V _{OH}	V _I = V _{T+} or V _{T-}	I _O =-100uA; V _{CC} =1.2V	-	1.2	-	V
			I _O =-100uA; V _{CC} =2.0V	1.8	2.0	-	V
			I _O =-100uA; V _{CC} =2.7V	2.5	2.7	-	V
			I _O =-100uA; V _{CC} =3.0V	2.8	3.0	-	V
			I _O =-100uA; V _{CC} =4.5V	4.3	4.5	-	V
			I _O =-6mA; V _{CC} =3.0V	2.4	2.82	-	V
			I _O =-12mA; V _{CC} =4.5V	3.6	4.2	-	V
LOW-level output voltage	V _{OL}	V _I = V _{T+} or V _{T-}	I _O =100uA; V _{CC} =1.2V	-	0	-	V
			I _O =100uA; V _{CC} =2.0V	-	0	0.2	V
			I _O =100uA; V _{CC} =2.7V	-	0	0.2	V
			I _O =100uA; V _{CC} =3.0V	-	0	0.2	V
			I _O =100uA; V _{CC} =4.5V	-	0	0.2	V
			I _O =6mA; V _{CC} =3.0V	-	0.25	0.40	V
			I _O =12mA; V _{CC} =4.5V	-	0.35	0.55	V
input leakage current	I _I	V _I =V _{CC} or GND; V _{CC} =5.5V		-	-	1.0	uA
supply current	I _{CC}	V _I =V _{CC} or GND; I _O =0A; V _{CC} =5.5V		-	-	20	uA
additional supply current	ΔI _{CC}	per input; V _I =V _{CC} -0.6V; V _{CC} =2.7V to 3.6V		-	-	500	uA
input capacitance	C _I	-		-	3.5	-	pF

Note: Typical values are measured at $T_{amb} = 25^{\circ}\text{C}$.

**3.3.2、DC Characteristics 2**(T_{amb}=-40°C to +125°C, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level output voltage	V _{OH}	V _I = V _{T+} or V _{T-}	I _O =-100uA; V _{CC} =2.0V	1.8	-	-	V
			I _O =-100uA; V _{CC} =2.7V	2.5	-	-	V
			I _O =-100uA; V _{CC} =3.0V	2.8	-	-	V
			I _O =-100uA; V _{CC} =4.5V	4.3	-	-	V
			I _O =-6mA; V _{CC} =3.0V	2.2	-	-	V
			I _O =-12mA; V _{CC} =4.5V	3.5	-	-	V
LOW-level output voltage	V _{OL}	V _I = V _{T+} or V _{T-}	I _O =100uA; V _{CC} =2.0V	-	-	0.2	V
			I _O =100uA; V _{CC} =2.7V	-	-	0.2	V
			I _O =100uA; V _{CC} =3.0V	-	-	0.2	V
			I _O =100uA; V _{CC} =4.5V	-	-	0.2	V
			I _O =6mA; V _{CC} =3.0V	-	-	0.50	V
			I _O =12mA; V _{CC} =4.5V	-	-	0.65	V
input leakage current	I _I	V _I =V _{CC} or GND; V _{CC} =5.5V		-	-	1.0	uA
supply current	I _{CC}	V _I =V _{CC} or GND; I _O =0A; V _{CC} =5.5V		-	-	40	uA
additional supply current	ΔI _{CC}	per input; V _I =V _{CC} -0.6V; V _{CC} =2.7V to 3.6V		-	-	850	uA

Note: Typical values are measured at T_{amb}=25°C.**3.3.3、AC Characteristics 1**(T_{amb}=-40°C to +85°C, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
nA to nY; propagation delay	t _{pd}	see Figure 5	V _{CC} =1.2V	-	80	-	ns
			V _{CC} =2.0V	-	27	37	ns
			V _{CC} =2.7V	-	20	28	ns
			V _{CC} =3.0V to 3.6V; C _L =15pF	-	13	-	ns
			V _{CC} =3.0V to 3.6V	-	15	22	ns
			V _{CC} =4.5V to 5.5V	-	-	18	ns
Power dissipation capacitance	C _{PD}	C _L =50pF; f _i =1MHz; V _I = GND to V _{CC}		-	15	-	pF

Note:

[1] Typical values are measured at T_{amb}=25°C.[2] t_{pd} is the same as t_{PLH} and t_{PHL}.[3] Typical values are measured at nominal supply voltage (V_{CC}=3.3V).[4] C_{PD} is used to determine the dynamic power dissipation (P_D in uW).P_D=C_{PD}×V_{CC}²×f_i×N+ ∑(C_L×V_{CC}²×f_o) where:f_i=input frequency in MHz;f_o=output frequency in MHz;C_L=output load capacitance in pF;

N=number of inputs switching;



V_{CC} =supply voltage in V.

3.3.4、AC Characteristics 2

($T_{amb}=-40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
nA to nY; propagation delay	t_{pd}	see Figure 5	$V_{CC}=2.0\text{V}$	-	-	48 ns
			$V_{CC}=2.7\text{V}$	-	-	35 ns
			$V_{CC}=3.0\text{V}$ to 3.6V	-	-	28 ns
			$V_{CC}=4.5\text{V}$ to 5.5V	-	-	23 ns

Note:

[1] Typical values are measured at $T_{amb}=25^{\circ}\text{C}$.

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] Typical values are measured at nominal supply voltage ($V_{CC}=3.3\text{V}$).

3.3.5、Transfer Characteristics 1

($T_{amb}=-40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
positive-going threshold voltage	V_{T+}	see Figure 6 and Figure 7	$V_{CC}=1.2\text{V}$	-	0.70	- V
			$V_{CC}=2.0\text{V}$	0.8	1.10	1.4 V
			$V_{CC}=2.7\text{V}$	1.0	1.45	2.0 V
			$V_{CC}=3.0\text{V}$	1.2	1.60	2.2 V
			$V_{CC}=3.6\text{V}$	1.5	1.95	2.4 V
			$V_{CC}=4.5\text{V}$	1.7	2.50	3.15 V
			$V_{CC}=5.5\text{V}$	2.1	3.00	3.85 V
negative-going threshold voltage	V_{T-}	see Figure 6 and Figure 7	$V_{CC}=1.2\text{V}$	-	0.34	- V
			$V_{CC}=2.0\text{V}$	0.3	0.65	0.9 V
			$V_{CC}=2.7\text{V}$	0.4	0.90	1.4 V
			$V_{CC}=3.0\text{V}$	0.6	1.05	1.5 V
			$V_{CC}=3.6\text{V}$	0.8	1.30	1.8 V
			$V_{CC}=4.5\text{V}$	0.9	1.60	2.0 V
			$V_{CC}=5.5\text{V}$	1.1	2.00	2.6 V
hysteresis voltage	V_H	see Figure 6 and Figure 7	$V_{CC}=1.2\text{V}$	-	0.3	- V
			$V_{CC}=2.0\text{V}$	0.2	0.55	0.8 V
			$V_{CC}=2.7\text{V}$	0.3	0.60	1.1 V
			$V_{CC}=3.0\text{V}$	0.4	0.65	1.2 V
			$V_{CC}=3.6\text{V}$	0.4	0.70	1.2 V
			$V_{CC}=4.5\text{V}$	0.4	0.80	1.4 V
			$V_{CC}=5.5\text{V}$	0.6	1.00	1.5 V

Note: All typical values are measured at $T_{amb}=25^{\circ}\text{C}$.



3.3.6、Transfer Characteristics 2

($T_{amb} = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
positive-going threshold voltage	V _{T+}	see Figure 6 and Figure 7	V _{CC} =2.0V	0.8	-	1.4	V
			V _{CC} =2.7V	1.0	-	2.0	V
			V _{CC} =3.0V	1.2	-	2.2	V
			V _{CC} =3.6V	1.5	-	2.4	V
			V _{CC} =4.5V	1.7	-	3.15	V
			V _{CC} =5.5V	2.1	-	3.85	V
negative-going threshold voltage	V _{T-}	see Figure 6 and Figure 7	V _{CC} =2.0V	0.3	-	0.9	V
			V _{CC} =2.7V	0.4	-	1.4	V
			V _{CC} =3.0V	0.6	-	1.5	V
			V _{CC} =3.6V	0.8	-	1.8	V
			V _{CC} =4.5V	0.9	-	2.0	V
			V _{CC} =5.5V	1.1	-	2.6	V
hysteresis voltage	V _H	see Figure 6 and Figure 7	V _{CC} =2.0V	0.2	-	0.8	V
			V _{CC} =2.7V	0.3	-	1.1	V
			V _{CC} =3.0V	0.4	-	1.2	V
			V _{CC} =3.6V	0.4	-	1.2	V
			V _{CC} =4.5V	0.4	-	1.4	V
			V _{CC} =5.5V	0.6	-	1.5	V

Note: All typical values are measured at $T_{amb}=25^{\circ}\text{C}$.

4、Testing Circuit

4.1、AC Testing Circuit

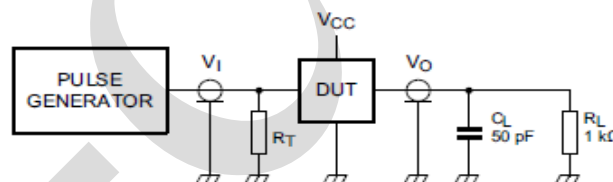


Figure 4. Test circuit for measuring switching times

Definitions for test circuit:

C_L =Load capacitance including jig and probe capacitance.

R_L =Load resistance.

R_T =Termination resistance should be equal to the output impedance Z_o of the pulse generator.



4.2、AC Testing Waveforms

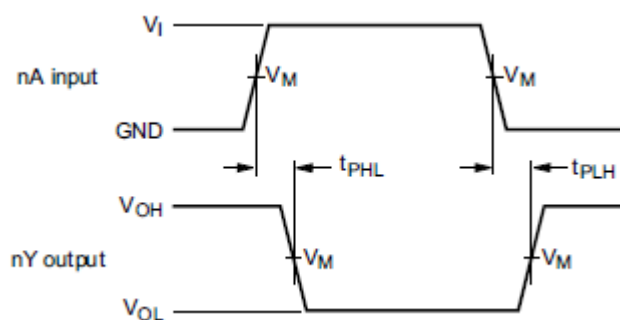


Figure 5. The input (nA) to output (nY) propagation delays

4.3、Transfer Characteristics Waveforms

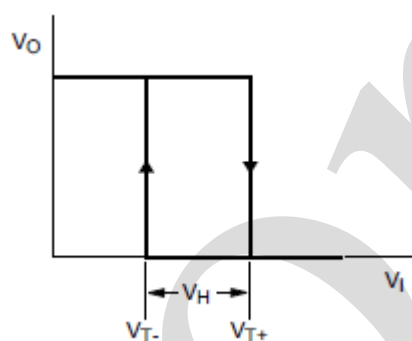


Figure 6. Transfer characteristics

V_{T+} and V_{T-} limits at 70% and 20%:

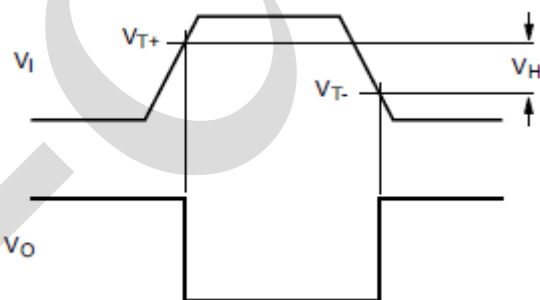


Figure 7. Definition of V_{T+} , V_{T-} and V_H

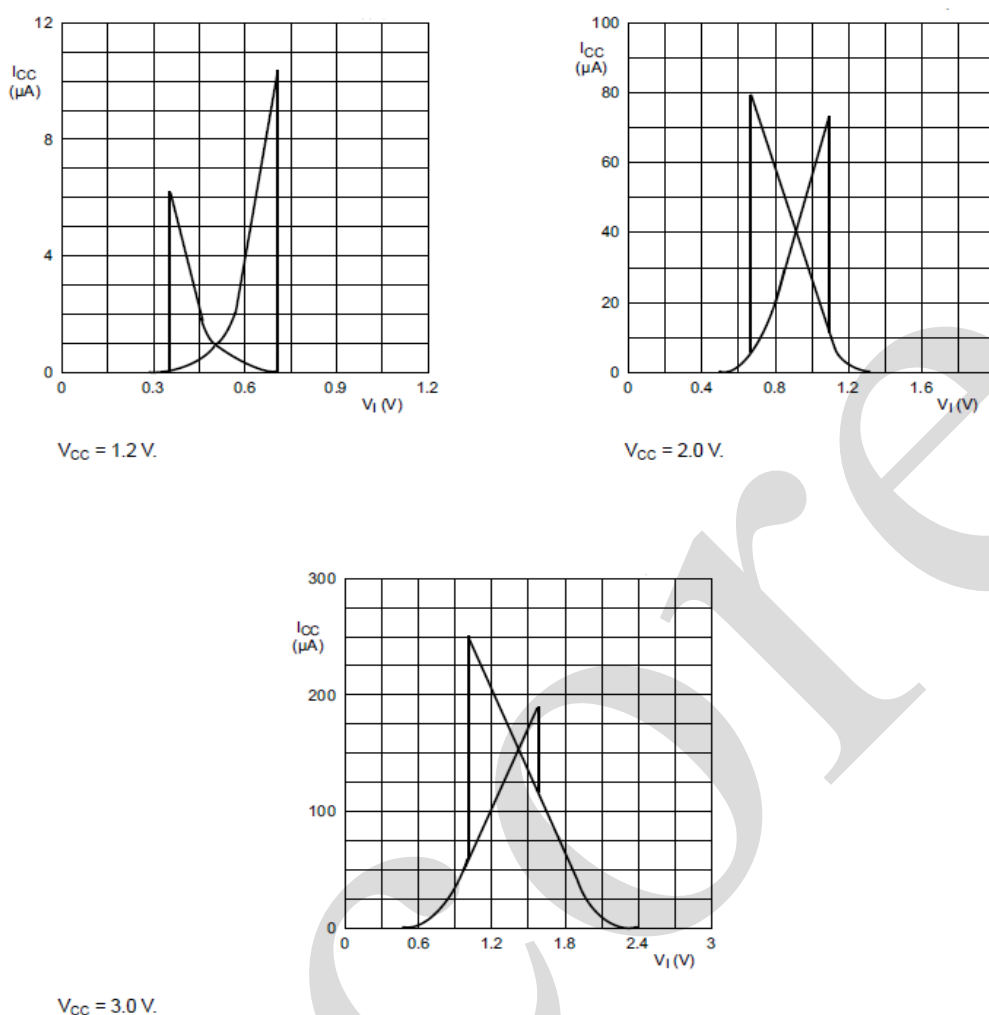


Figure 8. Typical transfer characteristics

4.4、Measurement Points

Supply voltage	Input	Output
V_{CC}	V_M	V_M
$<2.7V$	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.7V to 3.6V	1.5V	1.5V
$\geq 4.5V$	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$

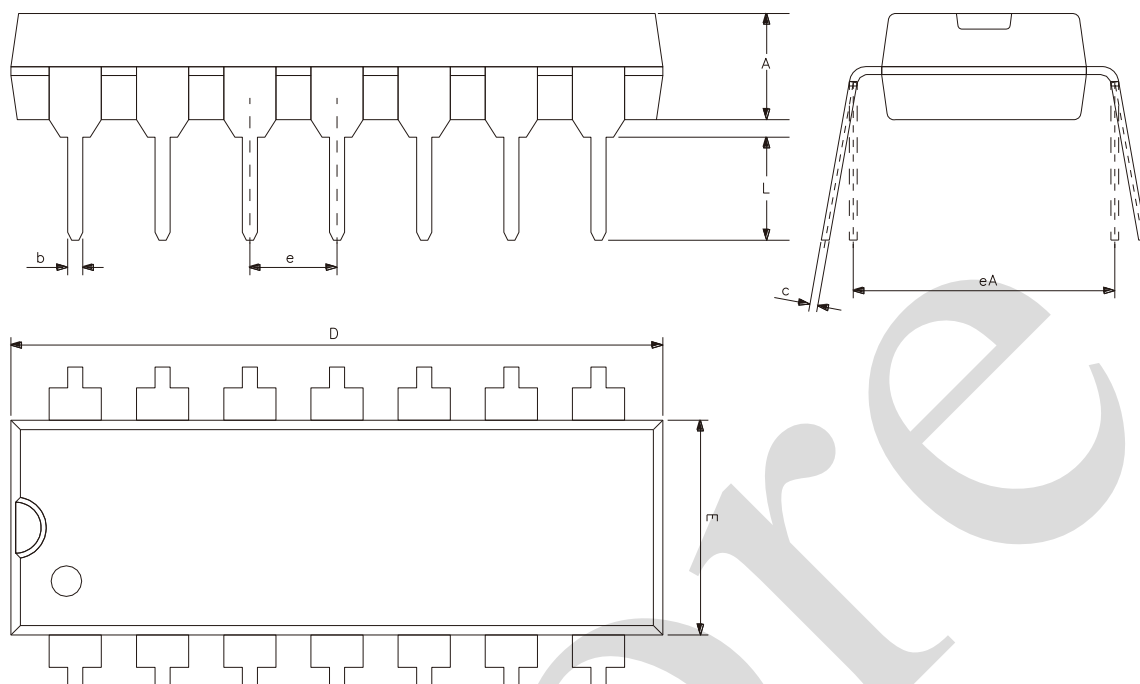
4.5、Test Data

Supply voltage	Input	
V_{CC}	V_I	t_r, t_f
$<2.7V$	V_{CC}	$\leq 2.5ns$
2.7V to 3.6V	2.7V	$\leq 2.5ns$
$\geq 4.5V$	V_{CC}	$\leq 2.5ns$



5、Package Information

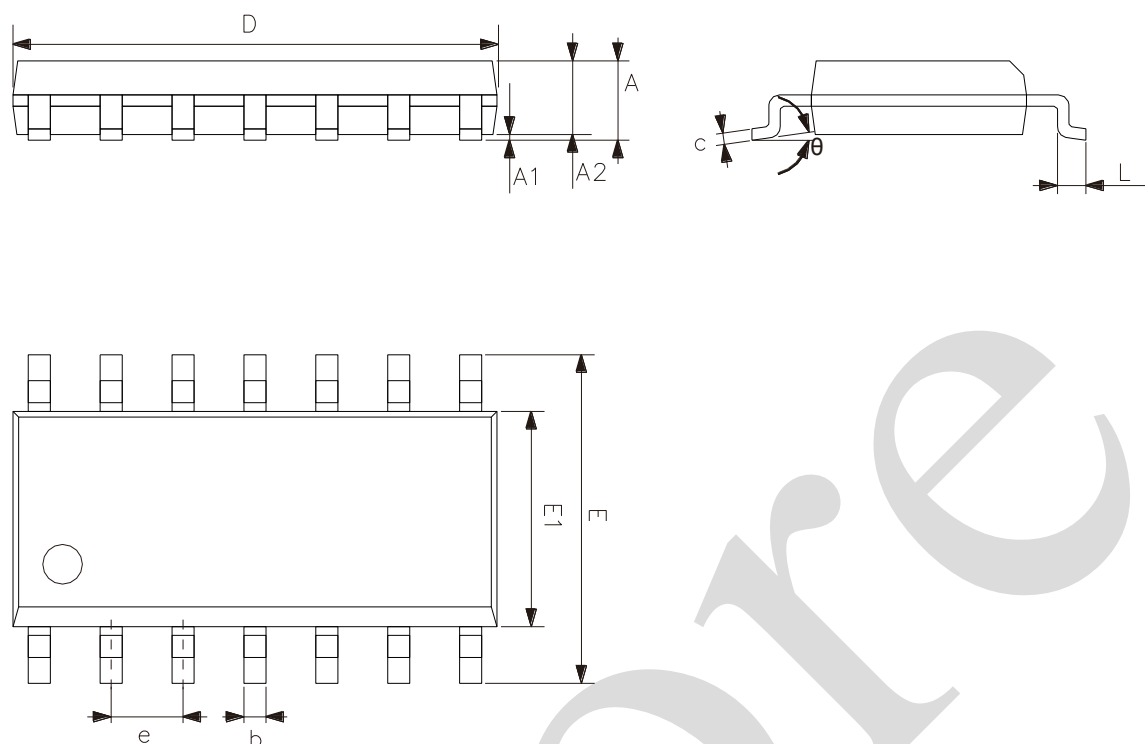
5.1、DIP14



Symbol	Dimensions (mm)	
	Min.	Max.
A	3.05	3.60
b	0.33	0.56
c	0.20	0.36
D	18.80	19.40
E	6.20	6.60
e	2.54	
eA	7.62	10.90
L	2.92	-



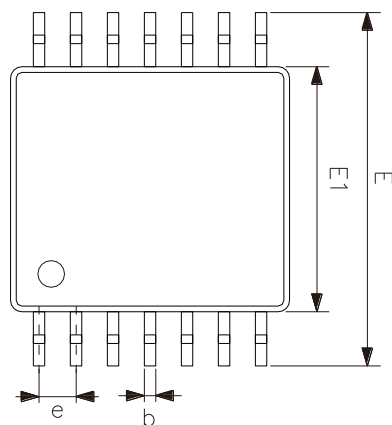
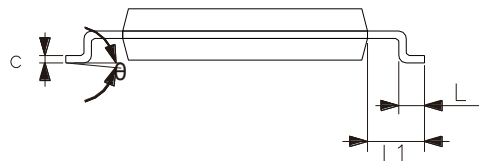
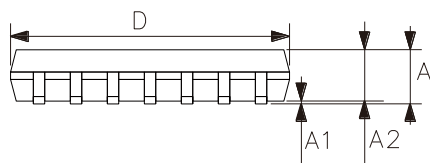
5.2、SOP14



Symbol	Dimensions (mm)	
	Min.	Max.
A	1.50	1.75
A1	0.05	0.25
A2	1.30	-
b	0.33	0.50
c	0.19	0.25
D	8.43	8.76
E	5.80	6.25
E1	3.75	4.00
e	1.27	
L	0.40	0.89
θ	0°	8°



5.3、TSSOP14



Symbol	Dimensions (mm)	
	Min.	Max.
A	-	1.20
A1	0.05	0.15
A2	0.80	1.05
b	0.19	0.30
c	0.09	0.20
D	4.90	5.10
E1	4.30	4.50
E	6.20	6.60
e	0.65	
L	0.45	0.75
L1	1.00	
θ	0 °	8 °



6、Statements And Notes

6.1、The name and content of Hazardous substances or Elements in the product

Part name	Hazardous substances or Elements									
	Lead and lead compounds	Mercury and mercury compounds	Cadmium and cadmium compounds	Hexavalent chromium compounds	Polybrominated biphenyls	Polybrominated biphenyl ethers	Dibutyl phthalate	Butylbenzyl phthalate	Di-2-ethylhexyl phthalate	Diisobutyl phthalate
Lead frame	○	○	○	○	○	○	○	○	○	○
Plastic resin	○	○	○	○	○	○	○	○	○	○
Chip	○	○	○	○	○	○	○	○	○	○
The lead	○	○	○	○	○	○	○	○	○	○
Plastic sheet installed	○	○	○	○	○	○	○	○	○	○
explanation	○: Indicates that the content of hazardous substances or elements in the detection limit of the following the SJ/T11363-2006 standard. ×: Indicates that the content of hazardous substances or elements exceeding the SJ/T11363-2006 Standard limit requirements.									

6.2、Notes

We Recommend you to read this chapter carefully before using this product.

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